



Advanced CMOS TTL Input – 74ACT05

Hex Inverter Gate with Open-Drain Outputs in bare die form

Rev 1.0
10/05/19

Description

The 74ACT05 hex inverter gate is fabricated on a 1.5µm advanced 5V CMOS process combining high speed LSTTL performance with CMOS low power. The device contains six independent inverters with open-drain outputs and perform the Boolean function $Y = \bar{A}$. Device outputs can connect with other open-drain outputs to form active LOW wired-OR or active HIGH wired-AND logic functions. Open-drain outputs need pull-up resistors to perform correctly*. Inputs are directly compatible with both standard TTL and CMOS outputs.

Features:

- Inputs directly accept TTL
- Outputs directly interface CMOS, NMOS and TTL
- Outputs Source/Sink 24 mA
- Low Input Current: 1µA
- Functionally compatible with bipolar 74LS05
- Lower power alternative to bipolar logic.

Ordering Information

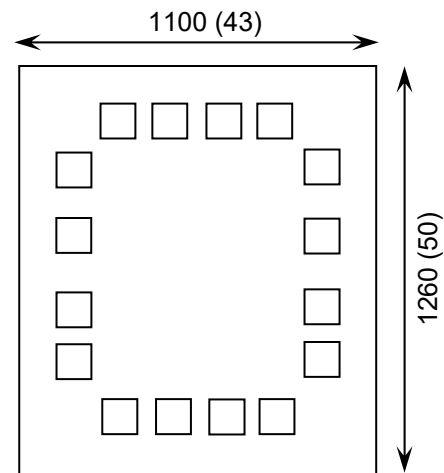
The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection

For High Reliability versions of this product please see

[54ACT05](#)

Die Dimensions in µm (mils)



Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <=> 350µm(14 Mils) – On request
- Assembled into Ceramic Package – On request

Mechanical Specification

Die Size (Unsawn)	1100 x 1260 43 x 50	µm mils
Minimum Bond Pad Size	108 x 108 4.25 x 4.25	µm mils
Die Thickness	350 (±20) 13.78 (±0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µm	
Back Metal Composition	N/A – Bare Si	

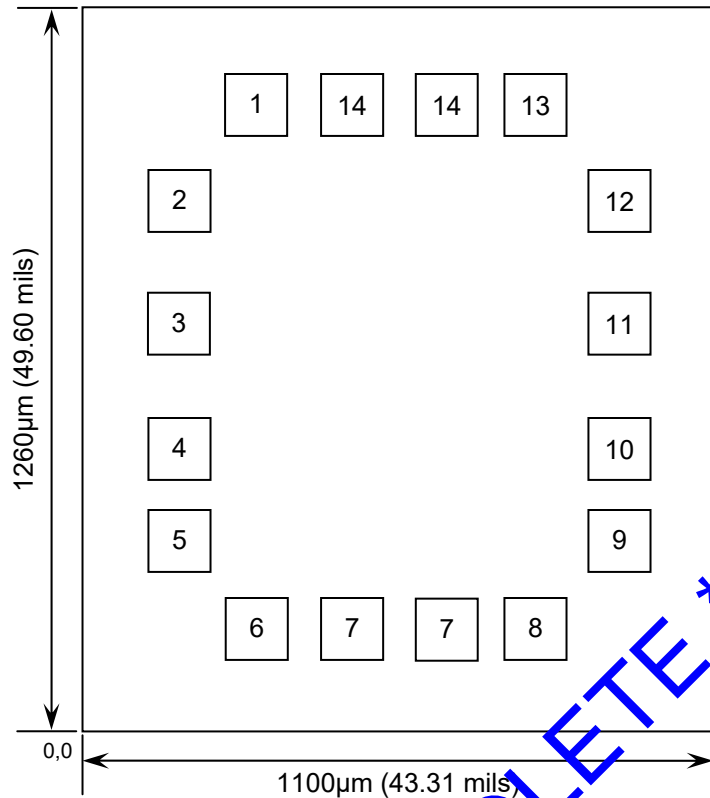




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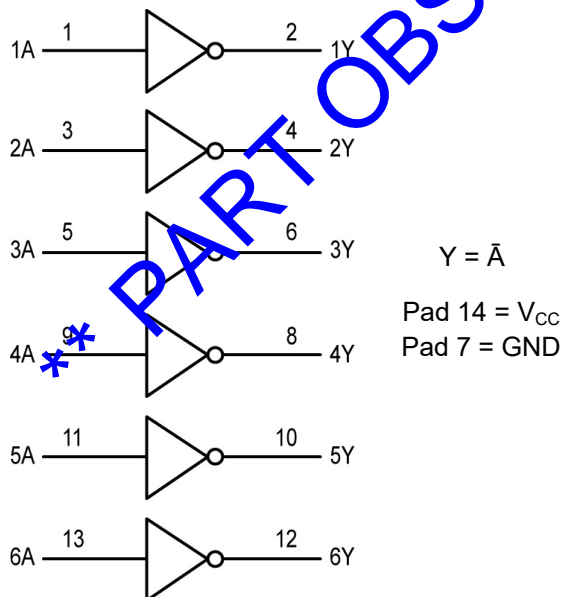
Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)	
		X	Y
1	1A	260	1035
2	1Y	120	865
3	2A	120	700
4	2Y	120	480
5	3A	120	255
6	3Y	260	115
7	GND	425	115
7	GND	580	115
8	4Y	745	115
9	4A	880	255
10	5Y	880	480
11	5A	880	700
12	6Y	880	865
13	6A	745	1035
14	V _{CC}	580	1035
14	V _{CC}	420	1035

CONNECT CHIP BACK TO V_{CC} OR FLOAT

Logic Diagram



Truth Table

INPUTS	OUTPUT
A	Y
H	L
L	Z

H = High level (steady state)
L = Low level (steady state)
Z = High-impedance off-state





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Absolute Maximum Ratings¹

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to GND)	V_{CC}	-0.5 to +7.0	V
DC Input Voltage (Referenced to GND)	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC Output Voltage (Referenced to GND)	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
DC Input Current	I_{IN}	± 20	mA
DC Output Current, per pad	I_{OUT}	± 50	mA
DC Supply Current, V_{CC} or GND, per pad	I_{CC}	± 50	mA
Power Dissipation in Still Air ²	P_D	750	mW
Storage Temperature Range	T_{STG}	-65 to 150	°C

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

Recommended Operating Conditions³ (Voltages Referenced to GND)

PARAMETER	SYMBOL	MIN	MAX	UNITS	
DC Supply Voltage	V_{CC}	4.5	5.5	V	
DC Input or Output Voltage	V_{IN}, V_{OUT}	0	V_{CC}	V	
Operating Temperature Range	T_J	-40	+85	°C	
Output current - High	I_{OH}	-	-24	mA	
Output current - Low	I_{OL}	-	24	mA	
Input Rise or Fall rate (V_{IN} from 0.8V to 2V)	$\Delta V / \Delta t$	$V_{CC} = 4.5V$	0	10	ns/V
		$V_{CC} = 5.5V$	0	10	

3. This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC Electrical Characteristics (Voltages referenced to GND)

PARAMETER	SYMBOL	V_{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Minimum High-Level Input Voltage	V_{IH}	4.5V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	2	2	2	V
		5.5V		2	2	2	
Maximum Low-Level Input Voltage	V_{IL}	4.5V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	0.8	0.8	0.8	V
		5.5V		0.8	0.8	0.8	
Minimum Low-Level Output Voltage	V_{OL}	4.5V	$I_{OUT} = 50\mu A$	0.1	0.1	0.1	V
		5.5V		0.1	0.1	0.1	
		4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ ⁵ $I_{OL} = 24mA$	0.36	0.44	0.44	V
		5.5V		0.36	0.44	0.44	

4. $-40^\circ C \leq T_J \leq +85^\circ C$ 5. All outputs loaded; thresholds on input associated with output under test.





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DC Electrical Characteristics Continued (Voltages referenced to GND)

PARAMETER	SYMBOL	V _{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁶	
Maximum Input Leakage Current	I _{IN}	5.5V	V _{IN} = V _{CC} or GND	±0.1	±1.0	±1.0	µA
Additional Maximum I _{CC} / Input	ΔI _{CCT}	5.5V	V _{IN} = V _{CC} - 2.1V	2.4	2.8	3	mA
Minimum Dynamic Output Current ⁶	I _{OLD}	5.5V	V _{OLD} = 1.65V Max	-	75	50	mA
	I _{OHD}	5.5V	V _{OHD} = 3.85V Min	-	-75	-50	
Maximum Quiescent Supply Leakage Current	I _{CC}	5.5V	V _{IN} = V _{CC} or GND I _{OUT} = 0µA	4	10	80	µA

6. Maximum test duration 2ms, one output loaded at a time.

AC Electrical Characteristics⁷ V_{CC} = 5.0V ±0.5V

PARAMETER	SYMBOL	V _{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Maximum Propagation Delay, Output Enable (Figure 1)	t _{PZL}	5.0V	C _L = 50pF	8	8.5	9.3	ns
	t _{PLZ}	5.0V		8.5	9	10.8	
Maximum Input Capacitance	C _{IN}	5.0V	T _J = 25°C	TYPICAL			pF
				4.5			
Power Dissipation Capacitance	C _{PD}	5.0V	T _J = 25°C, C _L = 50pF	30			pF

7. Not production tested in die form, characterized by chip design and tested in package.

Switching Waveform

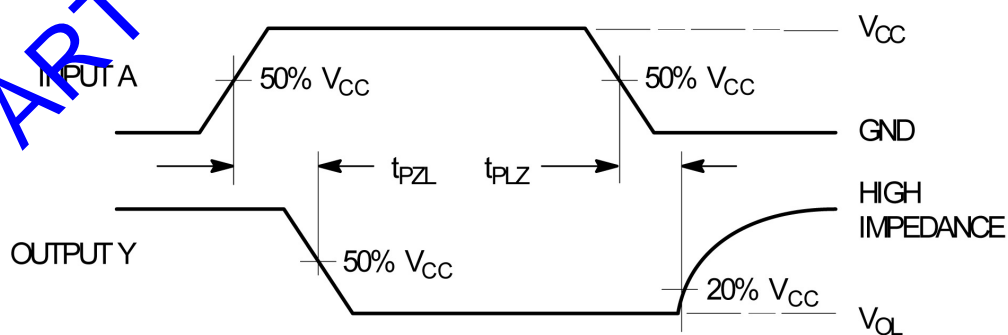


Figure 1 – Propagation Delay

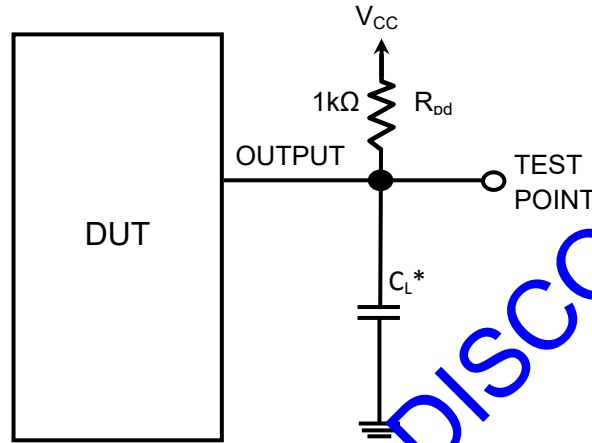




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Test Circuit



* Includes all probe and jig capacitance

Figure 2 - Test Circuit

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